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High Voltage Power MOSFET

N-Channel Enhancement Mode Avalanche Rated Fast Intrinsic Diode


| Symbol | Test Conditions | Maximum Ratings |  |
| :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {Dss }}$ | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$ | 1500 | V |
| $\mathrm{V}_{\text {DGR }}$ | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}, \mathrm{R}_{\mathrm{GS}}=1 \mathrm{M} \Omega$ | 1500 | V |
| $\mathrm{V}_{\text {Gss }}$ | Continuous | $\pm 30$ | V |
| $\mathrm{V}_{\text {GSM }}$ | Transient | $\pm 40$ | V |
| $\mathrm{I}_{\mathrm{D} 25}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | 12 | A |
| $\underline{\mathrm{I}_{\mathrm{DM}}}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$, Pulse Width Limited by $\mathrm{T}_{\mathrm{JM}}$ | 40 | A |
| $\mathrm{I}_{\mathrm{A}}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | 6 | A |
| $\mathrm{E}_{\text {AS }}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | 750 | mJ |
| dv/dt | $\mathrm{I}_{\mathrm{S}} \leq \mathrm{I}_{\mathrm{DM}}, \mathrm{V}_{\mathrm{DD}} \leq \mathrm{V}_{\text {DSS }}, \mathrm{T}_{J} \leq 150^{\circ} \mathrm{C}$ | 5 | V/ns |
| $\mathrm{P}_{\mathrm{D}}$ | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ | 890 | W |
|  |  | - $55 \ldots+150$ | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {JM }}$ |  | 150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {stg }}$ |  | $-55 \ldots+150$ | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\mathrm{L}}$ | 1.6 mm (0.062 in.) From Case for 10s | 300 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {soLD }}$ | Plastic Body for 10s | 260 | ${ }^{\circ} \mathrm{C}$ |
| $M_{d}$ | Mounting Torque | 1.13 / 10 | Nm/lb.in. |
| Weight | TO-268 | 4.0 | g |
|  | TO-247 | 6.0 | g |


| $\begin{aligned} & \text { Symbol } \quad \text { Test Conditions } \\ & \left(\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C} \text {, Unless Otherwise Specified }\right) \end{aligned}$ |  | Characteristic Values |  |  |
| :---: | :---: | :---: | :---: | :---: |
|  |  | Min. | Typ. | Max. |
| $\mathrm{BV}_{\mathrm{Dss}}$ | $\mathrm{V}_{\mathrm{GS}}=0 \mathrm{~V}, \mathrm{I}_{\mathrm{D}}=1 \mathrm{~mA}$ | 1500 |  | V |
| $\mathrm{V}_{\mathrm{GS}(\mathrm{th})}$ | $V_{\text {DS }}=V_{G S}, I_{D}=250 \mu \mathrm{~A}$ | 2.5 |  | 4.5 V |
| $\mathrm{I}_{\text {GSS }}$ | $\mathrm{V}_{\mathrm{GS}}= \pm 30 \mathrm{~V}, \mathrm{~V}_{\text {DS }}=0 \mathrm{~V}$ |  |  | $\pm 100 \mathrm{nA}$ |
| $\mathrm{I}_{\text {DS }}$ | $\mathrm{V}_{\mathrm{DS}}=\mathrm{V}_{\mathrm{DSS}}, \mathrm{V}_{\mathrm{GS}}=0 \mathrm{~V} \quad \mathrm{~T}_{\mathrm{J}}=125^{\circ} \mathrm{C}$ |  |  | $\begin{array}{r} 25 \mu \mathrm{~A} \\ 500 \mu \mathrm{~A} \end{array}$ |
| $\underline{\mathbf{R}_{\text {DS(on) }}}$ | $\mathrm{V}_{\mathrm{GS}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{D}}=0.5 \cdot \mathrm{I}_{\mathrm{D} 25}$, Note 1 |  |  | $2.2 \Omega$ |



TO-268 (IXTT)


$$
\mathrm{G}=\text { Gate } \quad \mathrm{D}=\text { Drain }
$$

$$
S=\text { Source } \quad \text { Tab }=\text { Drain }
$$

## Features

- International Standard Packages
- Molding Epoxies Weet UL 94 V-0 Flammability Classification
- Fast Intrinsic Diode
- Low Package Inductance


## Advantages

- Easy to Mount
- Space Savings
- High Power Density


## Applications

- High Voltage Power Supplies
- Capacitor Discharge
- Pulse Circuits



## Source-Drain Diode

| $\begin{aligned} & \text { Symbol Test Conditions } \\ & \left(\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}\right. \text {, Unless Otherwise Specified) } \end{aligned}$ |  | Characteristic Values |  |  |
| :---: | :---: | :---: | :---: | :---: |
|  |  | Min. ${ }^{\text {P }}$ Typ. | Max. |  |
| $\mathrm{I}_{\text {s }}$ | $\mathrm{V}_{\mathrm{GS}}=0 \mathrm{~V}$ |  | 12 | A |
| $\mathrm{I}_{\text {SM }}$ | Repetitive, Pulse Width Limited by $\mathrm{T}_{\mathrm{JM}}$ |  | 48 | A |
| $\mathrm{V}_{\text {sD }}$ | $\mathrm{I}_{\mathrm{F}}=\mathrm{I}_{S}, \mathrm{~V}_{\mathrm{GS}}=0 \mathrm{~V}$, Note 1 |  | 1.4 | V |
| $\begin{aligned} & \mathbf{t}_{\mathrm{rr}} \\ & \mathrm{I}_{\mathrm{RM}} \\ & \mathbf{Q}_{\mathrm{RM}} \end{aligned}$ | $\left\{\begin{array}{l} I_{F}=6 \mathrm{~A},-\mathrm{di} / \mathrm{dt}=100 \mathrm{~A} / \mu \mathrm{S} \\ \mathrm{~V}_{\mathrm{R}}=100 \mathrm{~V}, V_{G S}=0 \mathrm{~V} \end{array}\right.$ | $\begin{array}{r} 1.2 \\ 24.5 \\ 14.8 \end{array}$ |  | $\mu \mathrm{S}$ A $\mu \mathrm{C}$ |

Note

1. Pulse test, $\mathrm{t} \leq 300 \mu \mathrm{~s}$, duty cycle, $\mathrm{d} \leq 2 \%$.


TO-247 Outline


Terminals: 1-Gate 2 - Drain

| Dim. | Millimeter |  | Inches |  |
| :--- | ---: | ---: | ---: | ---: |
|  | Min. | Max. | Min. | Max. |
| $\mathrm{A}_{2}$ | 4.7 | 5.3 | .185 | .209 |
| $\mathrm{~A}_{1}$ | 2.2 | 2.54 | .087 | .102 |
| $\mathrm{~A}_{2}$ | 2.2 | 2.6 | .059 | .098 |
| b | 1.0 | 1.4 | .040 | .055 |
| $\mathrm{~b}_{1}$ | 1.65 | 2.13 | .065 | .084 |
| $\mathrm{~b}_{2}$ | 2.87 | 3.12 | .113 | .123 |
| C | .4 | .8 | .016 | .031 |
| D | 20.80 | 21.46 | .819 | .845 |
| E | 15.75 | 16.26 | .610 | .640 |
| e | 5.20 | 5.72 | 0.205 | 0.225 |
| L | 19.81 | 20.32 | .780 | .800 |
| L 1 |  | 4.50 |  | .177 |
| $\varnothing \mathrm{P}$ | 3.55 | 3.65 | .140 | .144 |
| Q | 5.89 | 6.40 | 0.232 | 0.252 |
| R | 4.32 | 5.49 | .170 | .216 |
| S | 6.15 | BSC | 242 | BSC |

IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.

IXTT12N150 IXTH12N150

Fig. 1. Output Characteristics @ $\mathrm{T}_{\mathrm{J}}=\mathbf{2 5}{ }^{\circ} \mathrm{C}$


Fig. 3. R $_{\mathrm{DS}(o n)}$ Normalized to $\mathrm{I}_{\mathrm{D}}=6 \mathrm{~A}$ Value vs. Junction Temperature


Fig. 5. Maximum Drain Current vs.
Case Temperature


Fig. 2. Output Characteristics @ $\mathrm{T}_{\mathrm{J}}=125^{\circ} \mathrm{C}$


Fig. 4. R $\mathrm{RS}_{\mathrm{D}(\mathrm{on})}$ Normalized to $\mathrm{I}_{\mathrm{D}}=6 \mathrm{~A}$ Value vs. Drain Current


Fig. 6. Input Admittance


Fig. 7. Transconductance


Fig. 9. Gate Charge


Fig. 11. Forward-Bias Safe Operating Area


Fig. 8. Forward Voltage Drop of Intrinsic Diode


Fig. 10. Capacitance


Fig. 12. Maximum Transient Thermal Impedance


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